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NO.139 P.:

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PATENT

Attorney Docket No.: 021801-001110US

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

KYU HYUN CHOI

Application No.: 10/820,189

Filed: April 6, 2004

For: METHOD OF MANUFACTURING

NON-VOLATILE DRAM

Confirmation No.: 7411

Examiner: LEE, CALVIN

Art Unit: 2818

SUPPLEMENTAL INFORMATION DISCLOSURE STATEMENT

UNDER 37 CFR §1.97 and §1.98

Mail Stop Amendment Commissioner for Patents P.O. Box 1450 Alexandria, VA 22313-1450

Sir:

The references cited on attached form PTO/SB/08A and PTO/SB/08B are being called to the attention of the Examiner. Copies of the references [in compliance with the requirements of 37 CFR §1.98(a)(2)] are enclosed. It is respectfully requested that the cited references be expressly considered during the prosecution of this application, and the references be made of record therein and appear among the "references cited" on any patent to issue therefrom.

As provided for by 37 CFR §1.97(g) and (h), no inference should be made that the information and references cited are prior art merely because they are in this statement and no representation is being made that a search has been conducted or that this statement encompasses all the possible relevant information.

The Commissioner is authorized to deduct such fee from the undersigned's Deposit Account No. 20-1430. Please deduct any additional fees from, or credit any overpayment to, the above-noted Deposit Account.

Respectfully submitted,

Ardeshir Tabibi Reg. No. 48,750

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PTO/SB/08A&B (07-05)

Substitute for form 1449A&B/PTO				Complete if Known		
				Application Number	10/820,189	
	PRMATION			Filing Date	April 6, 2004	
STA	TEMENT 8	Y APPLIC	CANT	First Named Inventor	Choi, Kyu Hyun	
				Art Unit	2818	
	(Use as many sha	ets as necessary	)	Examiner Name	LEE, CALVIN	
Sheet	1	of	1	Attorney Docket Number	021801-001110US	

Examinor Initials*	Cite No.1	Document Number Number Kind Cede <sup>2 (Amarc)</sup>	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pagea, Columns, Lines, Where Relevant Passages or Relevant Figures Appear
	1	US 5,590,073	12/31/1996	Arakawa et al.	
	2	US 5,914,514	6/22/1999	Dejenfelt et al.	
	3	US 6,025,265	2/15/2000	Miller at al.	<del></del>
	4	US 6,058,043	5/2/2000	Houdt et al.	
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	6	US 6,153,517	11/28/2000	Chuang et al.	*
	7	US 6,255,164	7/3/2001	Liu et al.	
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	15	US 6,808,148	10/19/2004	Choi et al.	
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	17	US 2004/0057288	8/25/2004	Chen et al.	
	18 .	US 2004/0207025	10/21/2004	Chiba et al.	•
	19	US 2005/0170588	8/4/2005	Chol, Kyu Hyun	<del>*************************************</del>
	20	US 2005/0207199	9/22/2005	Chen et al.	

FOREIGN PATENT DOCUMENTS								
Examiner Initiats*	No.1	Fo Country Code <sup>3</sup>	reign Patent Do	cument    Kind Code <sup>#</sup> (# known)	Publication Date MM-DD-YYYY	Name of Patentee or Applicant of Cited Document	Pagas, Columns, Lines, Where Relevant Passages or Relevant Figures Appear	
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Applicant's unique citation designation number (optional). Applicant is to place a check mark here if English language Translation is attached.